Vishay Semiconductors





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AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS			
I _{F(AV)}	110 A		
V _R	30 V		
Package	AAP Gen 7 (TO-240AA)		
Circuit configuration	Two diodes doubler circuit		

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKDS220.. Schottky rectifier doubler has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	110	А		
V _{RRM}		30	V		
I _{FSM}	t _p = 5 μs sine	18 000	А		
V _F	110 A _{pk} , T _J = 125 °C	0.57	V		
TJ	Range	-55 to +150	C°		

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-VSKDS220/030	UNITS
Maximum DC reverse voltage	V _R	30	V
Maximum working peak reverse voltage	V _{RWM}	50	v



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ABSOLUTE MAXIMUM RATIN	GS				
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_{C} = 110 °C	, rectangular waveform	110	
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	18 000	А
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	2000	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 15 \text{ A}, L = 1 \text{ mH}$ 9		99	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim		22	А

ELECTRICAL SPECIFICATION	IS				
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
	$V_{FM} = \begin{array}{c} 110 \text{ A} \\ \hline 220 \text{ A} \\ \hline 110 \text{ A} \\ \hline 110 \text{ A} \\ \hline T_{J} = 25 \text{ °C} \\ \hline T_{J} = 125 \text{ °C} \\ \hline \end{array}$	110 A	T _J = 25 °C	0.59	v
Maximum forward voltage drop		220 A		0.78	
Maximum forward voltage drop		T 405.00	0.57	v	
		220 A	1j = 125 C	0.82	
Maximum reverse lookage averant	rse leakage current	T _J = 25 °C	V _R = Rated V _R	10	mA
Maximum reverse leakage current		T _J = 125 °C		650	mA
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		7400	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 100		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz 3000 (1 min) 3600 (1 s)		V	

THERMAL - MECHAN	CAL SPE	CIFICATI	ONS		
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.52	°C/W
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	0/10
Approvimato weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
	busbar		spread of the compound.		
Case style			JEDEC®	TO-240AA co	mpatible

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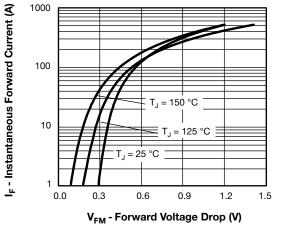
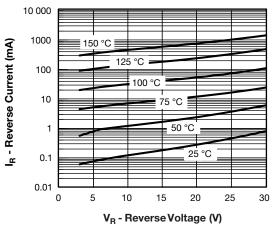
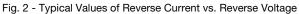


Fig. 1 - Maximum Forward Voltage Drop Characteristics





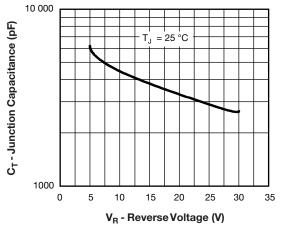


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

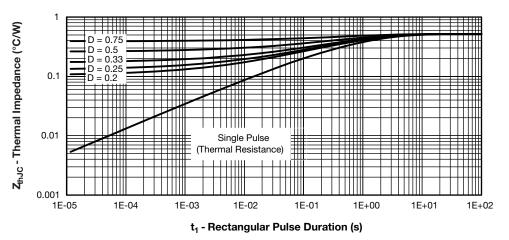


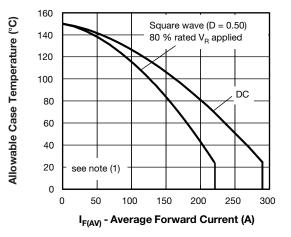
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

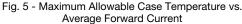
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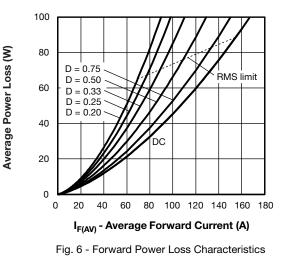
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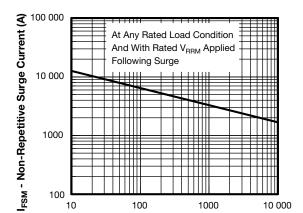


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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

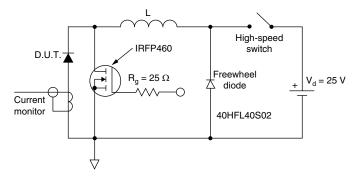


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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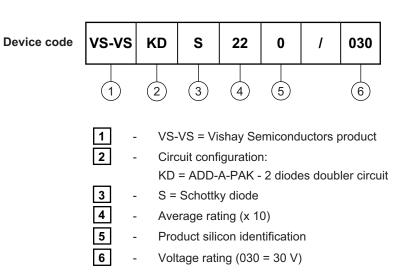
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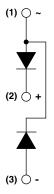
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ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



	ENTS
Dimensions	www.vishay.com/doc?95369

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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